## WHAT IS CLAIMED IS:

|                  | 1            | 1.  | An Infra Red (IR) sensing device comprising:                             |  |
|------------------|--------------|---|--|--|
|                  | 2            | an IR   | sensing element for detecting IR radiation, wherein the IR sensing       |  |
|                  | 3            | element includes a p  | lurality of thermopile elements with connections to both ends and to a   |  |
|                  | 4            | center point of the se  | ensing element;  |  |
|                  | 5            | a prod  | cessing circuit having two inputs coupled to the IR sensing element and  |  |
|                  | 6            | configured to receive   | e and analyze the electrical signals generated by the IR sensing element |  |
|                  | 7            | protec  | ction circuitry coupled to the two inputs and a first potential; and     |  |
| æi:              | 8            | an ele  | ctrically conducting housing connected to the first potential,           |  |
| =<br>=<br>=<br>= | 8<br>9<br>10 | where   | in the processor connects the center point of the sensing element to the |  |
|                  | 10           | first potential and the ends of the sensing element to the two inputs, wherein the processing |  |  |
|                  | 11           | circuit analyzes the s  | ignals from the ends of the sensing element as a differential pair of    |  |
|                  | 12           | signals relative to the   | first potential.   |  |
| 1.               | 1            | 2.  | The device of claim 1, wherein the processing circuit is embodied as     |  |
| 1.<br>]<br>]:    | 2            | an integrated circuit.  | The device of claim 1, wherein the processing eneur is embodied as       |  |
| <b>!</b> ;       | _            | an integrated enteut.   |  |  |
|                  | 1            | 3.  | The device of claim 2, wherein the first potential is connected to the   |  |
| •                | 2            | substrate of the integr   | rated circuit.   |  |
|                  | 1            | 4.  | The device of claim 1, wherein the processing circuit includes           |  |
|                  | 2            | configuration circuitr  |  |  |
|                  |              | <i>B</i>  | <b>,</b> .   |  |
|                  | 1            | 5.  | The device of claim 1, wherein the processing circuit includes           |  |
|                  | 2            | calibration circuitry.  |  |  |
|                  | 1            | 6.  | The device of claim 4 or 5, wherein the processing circuit includes a    |  |
|                  | 2            |   | for storing calibration or configuration data.                           |  |
|                  |              | <b>,</b>  | on comigaration data.  |  |
|                  | 1            | 7.  | The device of claim 6, wherein the non-volatile memory is                |  |
|                  | 2            | programmed after ma   | nufacture.   |  |
|                  | 1            | 8.  | The device of claim 6, wherein the non-volatile memory is                |  |
|                  | 2            | programmed after the  | device has been installed in its operating location.                     |  |
|                  | 1            |   |  |  |
|                  | 1            | 9.  | An Infra Red (IR) sensing device comprising:                             |  |

|             |   | 1      |
|-------------|---|--------|
|             |   | 4      |
|             |   | 4      |
|             |   | 2 4 6  |
|             |   | 7      |
|             |   | ٤      |
|             | 1 | ç      |
|             | 1 | (      |
| <u>ļ</u> .  | 1 | 1      |
|             |   | 1      |
| <b>ļi</b> . |   | 2      |
| u           |   | 1      |
| £ .         |   | 2      |
| Fil.        |   | 2<br>3 |
| ļ.          |   | ع      |
|             |   | 1      |
| •           |   | 2      |
|             |   |        |

| 2 | an IR sensing element for detecting IR radiation, wherein the IR sensing                        |  |  |  |  |
|---|---|--|--|--|--|
| 3 | element includes a plurality of serially connected thermopile elements;                         |  |  |  |  |
| 4 | a processing circuit configured to receive and process the electrical signals                   |  |  |  |  |
| 5 | generated by the thermopile elements, the processing circuit having first and second inputs     |  |  |  |  |
| 6 | coupled to the two ends of the series of thermopile elements and a third input coupled to a     |  |  |  |  |
| 7 | center point of the series of thermopile elements and to a first potential; and                 |  |  |  |  |
| 8 | protection circuitry coupled to the two inputs and the first potential;                         |  |  |  |  |
| 9 | wherein the processing circuit processes the signals at the first and second                    |  |  |  |  |
| 0 | inputs as a differential pair of signals relative to the first potential so as to produce a     |  |  |  |  |
| 1 | temperature readout signal.   |  |  |  |  |
| 1 | 10. The sensing device of claim 9, further comprising an electrically                           |  |  |  |  |
| 2 | conducting housing connected to the first potential.  |  |  |  |  |
| 1 | 11. The sensing device of claim 9, wherein the protection circuitry                             |  |  |  |  |
| 2 | includes a pair of diode structures, each diode structure coupled to the first potential and to |  |  |  |  |
| 3 | one of the first and second inputs.   |  |  |  |  |
| 1 | 12. The sensing device of claim 9, wherein the processing circuit is                            |  |  |  |  |
| 2 | implemented on a first integrated circuit.  |  |  |  |  |
|   |   |  |  |  |  |
| 1 | 13. The sensing device of claim 12, wherein the sensing element is                              |  |  |  |  |
| 2 | implemented on a second integrated circuit.   |  |  |  |  |
| 1 | 14. The sensing device of claim 12, wherein the protection circuitry is                         |  |  |  |  |
| 2 | implemented on the first integrated circuit.  |  |  |  |  |
| 1 | 15. The sensing device of claim 9, further comprising a conductive                              |  |  |  |  |

housing connected to the first potential.